

IAUT165N08S5N029ATMA2

IAUT165N08S5N029ATMA2 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IAUT165N08S5N029ATMA2 Specifications

Manufacturer Part Number	IAUT165N08S5N029ATMA2
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerSFN
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	80V
Current - Continuous Drain (Id) @ 25°C	165A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	6V, 10V
Vgs(th) (Max) @ Id	3.8V @ 108µA
Gate Charge (Qg) (Max) @ Vgs	90nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	6370pF @ 40V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	167W (Tc)
Rds On (Max) @ Id, Vgs	2.9 mOhm @ 80A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-HSOF-8-1
Package / Case	8-PowerSFN
	Report errors?

IAUT165N08S5N029ATMA2 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IAUT165N08S5N029ATMA2 Payment Methods



If you have any question about IAUT165N08S5N029ATMA2, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com